

## Silicon NPN Power Transistors

2SC4231

## DESCRIPTION

- With ITO-220 package
- Switching power transistor
- High voltage ,high speed

## PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

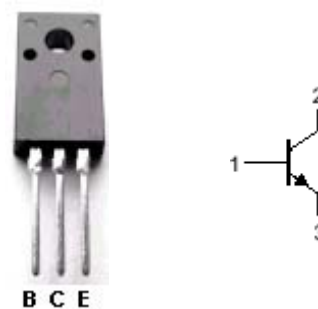


Fig.1 simplified outline (ITO-220) and symbol

Absolute maximum ratings( $T_a=25^{\circ}\text{C}$ )

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-base voltage	Open emitter	1200	V
$V_{CEO}$	Collector-emitter voltage	Open base	800	V
$V_{EBO}$	Emitter-base voltage	Open collector	7	V
$I_C$	Collector current		2	A
$I_{CM}$	Collector current-Peak		4	A
$I_B$	Base current		1	A
$I_{BM}$	Base current-Peak		2	A
$P_T$	Total power dissipation	$T_C=25^{\circ}\text{C}$	30	W
$T_j$	Junction temperature		150	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature		-55~150	$^{\circ}\text{C}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal resistance junction case	4.16	$^{\circ}\text{C}/\text{W}$

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## CHARACTERISTICS

T<sub>j</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE0(SUS)</sub>	Collector-emitter sustaining voltage	I <sub>C</sub> =0.1A; I <sub>B</sub> =0	800			V
V <sub>CEsat</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =1A; I <sub>B</sub> =0.2A			1.0	V
V <sub>BEsat</sub>	Base-emitter saturation voltage	I <sub>C</sub> =1A; I <sub>B</sub> =0.2A			1.5	V
I <sub>CBO</sub>	Collector cut-off current	At rated volatge			0.1	mA
I <sub>CEO</sub>	Collector cut-off current					
I <sub>EBO</sub>	Emitter cut-off current	At rated volatge			0.1	mA
h <sub>FE-1</sub>	DC current gain	I <sub>C</sub> =1A; V <sub>CE</sub> =5V	8			
h <sub>FE-2</sub>	DC current gain	I <sub>C</sub> =1mA; V <sub>CE</sub> =5V	7			
f <sub>T</sub>	Transition frequency	I <sub>C</sub> =0.2A; V <sub>CE</sub> =10V		8		MHz
t <sub>on</sub>	Turn-on time	I <sub>C</sub> =1; I <sub>B1</sub> =0.2A; I <sub>B2</sub> =0.4A; R <sub>L</sub> =250Ω V <sub>BB2</sub> =4V			0.5	μ s
t <sub>s</sub>	Storage time				3.5	μ s
t <sub>f</sub>	Fall time				0.3	μ s

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PACKAGE OUTLINE

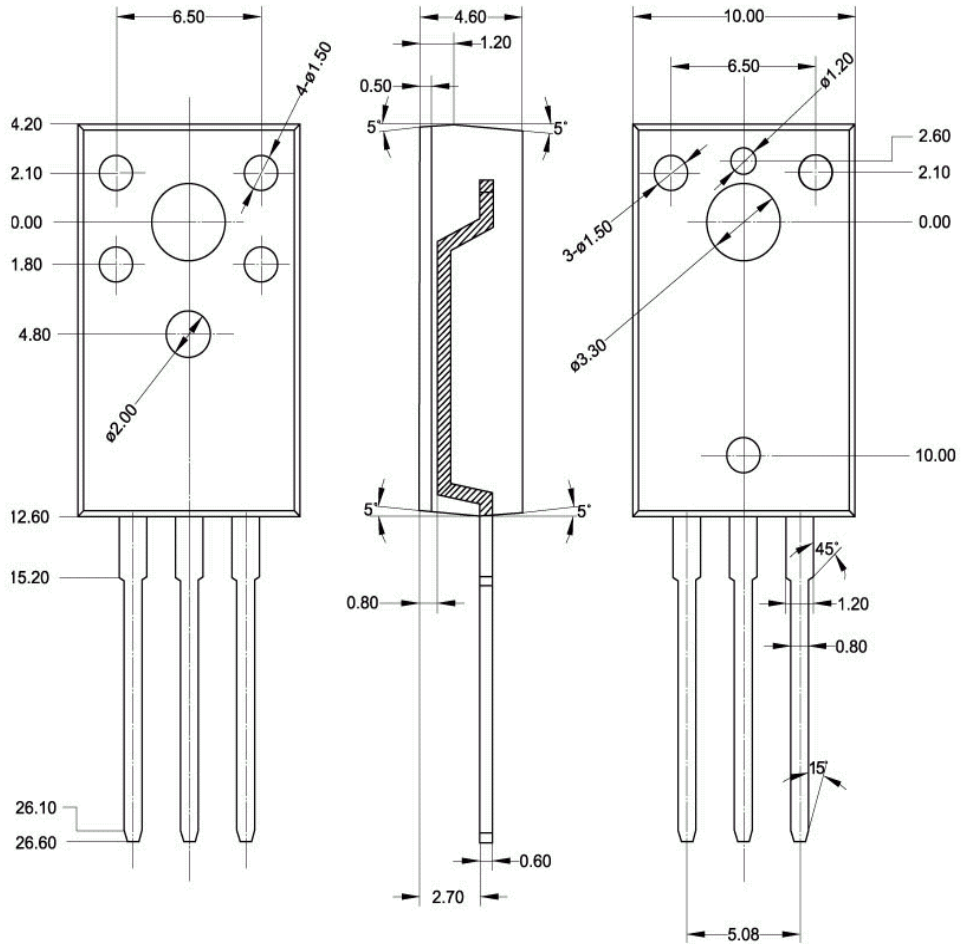


Fig.2 Outline dimensions (unindicated tolerance:  $\pm 0.20$  mm)